

60V N-CHANNEL SELF PROTECTED ENHANCEMENT MODE IntelliFET MOSFET

Product Summary

Continuous Drain Source Voltage: 60V

On-State Resistance: 500mΩ

Nominal Load Current (V_{IN} = 5V): 1.3A

Clamping Energy: 90mJ

Description

The ZXMS6004FF is a self-protected low side IntelliFET™ MOSFET with logic level input. It integrates overtemperature, overcurrent, overvoltage (active clamp) and ESD protected logic level functionality. The ZXMS6004FF is ideal as a general purpose switch driven from 3.3V or 5V microcontrollers in harsh environments where standard MOSFETs are not rugged enough.

Applications

- Especially Suited for Loads with a High In-Rush Current such as Lamps and Motors
- All Types of Resistive, Inductive and Capacitive Loads in Switching Applications
- µC Compatible Power Switch for 12V and 24V DC Applications
- Replaces Electromechanical Relays and Discrete Circuits
- Linear Mode Capability the current-limiting protection circuitry is designed to de-activate at low V_{DS} to minimize on state power dissipation. The maximum DC operating current is therefore determined by the thermal capability of the package/board combination, rather than by the protection circuitry. This does not compromise the product's ability to self-protect at low V_{DS}.

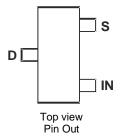
Features and Benefits

- Compact High Power Dissipation Package
- Low Input Current
- Logic Level Input (3.3V and 5V)
- Short Circuit Protection with Auto-Restart
- Overvoltage Protection (Active Clamp)
- Thermal Shutdown with Auto-Restart
- Overcurrent Protection
- Input Protection (ESD)
- High Continuous Current Rating
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (ZXMS6004FFQ)

Mechanical Data

- Case: SOT23F
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish @3
- Weight: 0.012 grams (Approximate)





Ordering Information (Note 4)

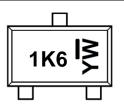
ſ	Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
	ZXMS6004FFTA	1K6	7	12	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

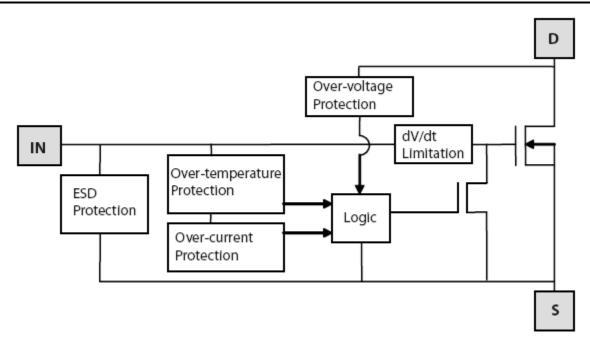


Marking Information



Y: Year: 0~9
W: Week: A-Z : 1~26
a~z: 27~52
z: Represents 52 & 53 Week
1K6 = Product Type Marking Code

Functional Block Diagram





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Continuous Drain-Source Voltage	V _{DS}	60	V
Drain-Source Voltage for Short Circuit Protection	V _{DS(SC)}	36	V
Continuous Input Voltage	V _{IN}	-0.5 +6	V
Continuous Input Current @-0.2V \leq V _{IN} \leq 6V Continuous Input Current @V _{IN} < -0.2V or V _{IN} > 6V	I _{IN}	No limit I _{IN} ≤2	mA
Pulsed Drain Current @V _{IN} = 3.3V	I _{DM}	2	A
Pulsed Drain Current @V _{IN} = 5V	I _{DM}	2.5	A
Continuous Source Current (Body Diode)	I _S	1	A
Pulsed Source Current (Body Diode)	I _{SM}	5	Α
Unclamped Single Pulse Inductive Energy, T _J = +25°C, I _D = 0.5A, V _{DD} = 24V	E _{AS}	90	mJ
Electrostatic Discharge (Human Body Model)	V _{ESD}	4,000	V
Charged Device Model	V_{CDM}	1,000	V

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Power Dissipation @T _A = +25°C (Note 5) Linear Derating Factor	P _D	0.83 6.66	W mW/°C
Power Dissipation @T _A = +25°C (Note 6) Linear Derating Factor	P _D	1.5 12.0	W mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	150	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	83	°C/W
Thermal Resistance, Junction to Case (Note 7)	R ₀ JC	44	°C/W
Operating Temperature Range	TJ	-40 to +150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

- 5. For a device surface mounted on 15mm x 15mm single sided, 1oz weight copper on 1.6mm FR4 board, in still air conditions. 6. For a device surface mounted on 50mm x 50mm single sided, 2oz weight copper on 1.6mm FR4 board, in still air conditions. 7. Thermal resistance from junction and the mounting surfaces of the drain pins.

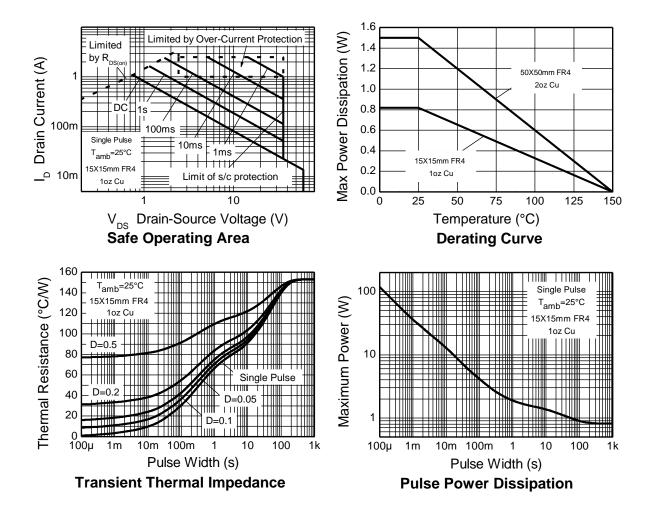
Recommended Operating Conditions

The ZXMS6004FF is optimized for use with μC operating from 3.3V and 5V supplies.

Characteristic	Symbol	Min	Max	Unit
Input Voltage Range	V_{IN}	0	5.5	V
Ambient Temperature Range	T _A	-40	+125	°C
High Level Input Voltage for MOSFET to be On	V _{IH}	3	5.5	V
Low Level Input Voltage for MOSFET to be Off	V_{IL}	0	0.7	V
Peripheral Supply Voltage (Voltage to which Load is Referred)	V_{P}	0	36	V



Typical Thermal Characteristics





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Static Characteristics							
Drain-Source Clamp Voltage	V _{DS(AZ)}	60	65	70	V	$I_D = 10mA$	
Off-State Drain Current	I _{DSS}	_	_	500	nA	$V_{DS} = 12V, V_{IN} = 0V$	
On-State Drain Current		_	_	1	μA	$V_{DS} = 36V, V_{IN} = 0V$	
Input Threshold Voltage	V _{IN(TH)}	0.7	1	1.5	V	$V_{DS} = V_{GS}$, $I_D = 1mA$	
Input Current		l	60	100	μA	$V_{IN} = +3V$	
input Current	I _{IN}	_	120	200		$V_{IN} = +5V$	
Input Current while Overtemperature Active	_	1	_	220	μA	$V_{IN} = +5V$	
Static Drain-Source On-State Resistance	J	_	400	600	mΩ	$V_{IN} = +3V$, $I_D = 0.5A$	
Static Dialii-Source Oil-State Resistance	R _{DS(ON)}	1	350	500	11122	$V_{IN} = +5V, I_D = 0.5A$	
Continuous Drain Current (Note 5)		0.9	_	_		$V_{IN} = 3V; T_A = +25^{\circ}C$	
Continuous Diam Current (Note 5)	─ I _D	1.0	_	_	А	$V_{IN} = 5V$; $T_A = +25$ °C	
Continuous Drain Current (Note 6)		1.2	_	_		$V_{IN} = 3V; T_A = +25^{\circ}C$	
Continuous Diam Current (Note 6)		1.3	_	_		$V_{IN} = 5V; T_A = +25^{\circ}C$	
Current Limit (Note 8)	I _{D(LIM)}	0.7	1.7	_	A	$V_{IN} = +3V$	
Current Limit (Note 8)		1	2.2	_		$V_{IN} = +5V$	
Dynamic Characteristics							
Turn-On Delay Time	t _{D(ON)}	1	5	_			
Rise Time	t _R	l	10	_	110	$V_{DD} = 12V$, $I_D = 0.5A$, $V_{GS} = 5V$	
Turn-Off Delay Time	t _{D(OFF)}	1	45	_	μs	$V_{DD} = 12V, I_D = 0.5A, V_{GS} = 5V$	
Fall Time	f _F	-	15	_			
Overtemperature Protection							
Thermal Overload Trip Temperature (Note 9)	T_{JT}	+150	+175		°C	_	
Thermal Hysteresis (Note 9)	f _F	_	+10	_	°C	_	

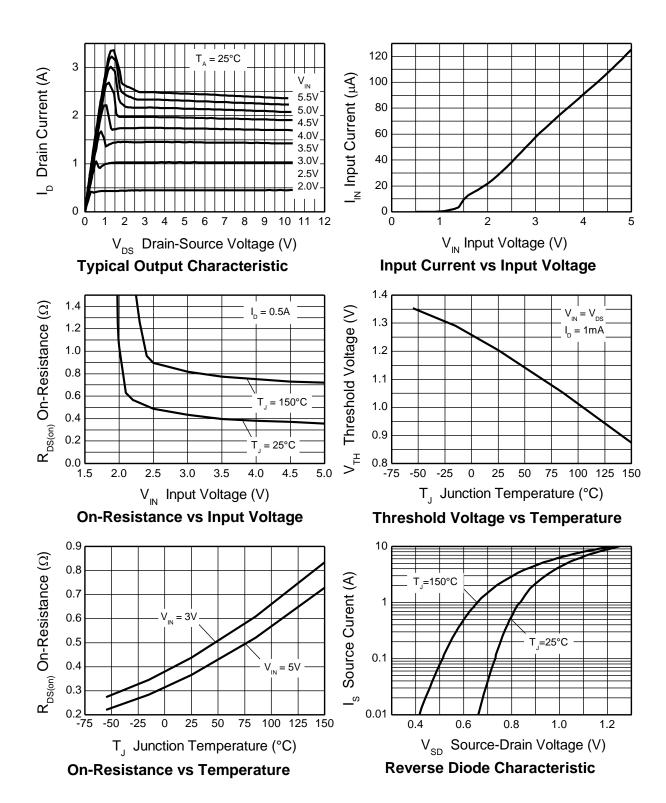
Notes:

^{8.} The drain current is restricted only when the device is in saturation (see graph 'Typical Output Characteristic'). This allows the device to be used in the fully on-state without interference from the current limit. The device is fully protected at all drain currents, as the low power dissipation generated outside saturation makes current limit unnecessary.

^{9.} Overtemperature protection is designed to prevent device destruction under fault conditions. Fault conditions are considered as "outside" normal operating range, so this part is not designed to withstand overtemperature for extended periods.

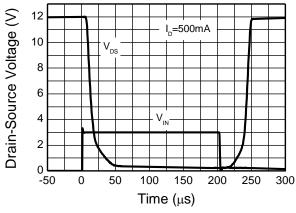


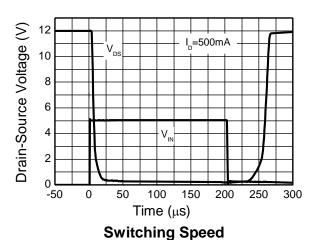
Typical Performance Characteristics



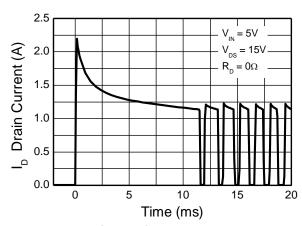


Typical Performance Characteristics (Continued)





Switching Speed



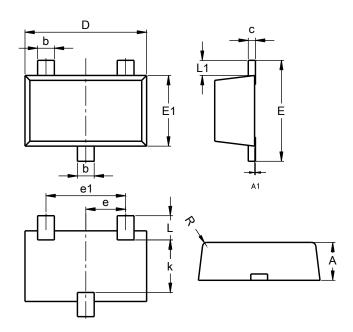
Typical Short Circuit Protection



Package Outline Dimensions

Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.

SOT23F

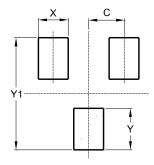


	SOT23F						
Dim	Min Max Typ						
Α	0.80	1.00	0.90				
b	0.35	0.50	0.44				
С	0.10	0.20	0.16				
D	2.80	3.00	2.90				
е		0.95 RE	F				
e1	(0.190 RI	EF				
Е	2.30	2.50	2.40				
E1	E1 1.50 1.70 1.6						
k 1.20							
L 0.30 0.65		0.50					
L1	0.30	0.50	0.40				
R	0.05	0.15	-				
All Dimensions in mm							

Suggested Pad Layout

 $Please see AP02001 \ at \ http://www.diodes.com/_files/datasheets/ap02001.pdf \ for \ the \ latest \ version.$

SOT23F



Dimensions	Value (in mm)		
С	0.95		
Х	0.80		
Υ	1.110		
Y1	3.000		



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